# NSN 5962-01-279-3738

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

Between 1.230 inches and 1.280 inches

#### **Body Width:**

Between 0.245 inches and 0.310 inches

# **Body Height:**

Between 0.140 inches and 0.175 inches

# Maximum Power Dissipation Rating:

660.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Monolithic and programmable and high speed

#### **Inclosure Material:**

Ceramic

# Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Complementary-metal oxide-semiconductor logic

#### Input Circuit Pattern:

14 input

# **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

45.00 nanoseconds propagation delay time, low to high level output and 45.00 nanoseconds propagation delay time, high to low level output

# Memory Device Type:

Rom

#### **Terminal Type And Quantity:**

24 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

### Fiig:

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